504271907 03/14/2017

PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1 Stylesheet Version v1.2 EPAS ID: PAT4318589

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
Feng-Yi Chang	03/14/2017
Fu-Che Lee	03/14/2017
Chien-Cheng Tsai	03/14/2017
Feng-Ming Huang	03/14/2017
Hsien-Shih Chu	03/14/2017

RECEIVING PARTY DATA

Name:	UNITED MICROELECTRONICS CORP.
Street Address:	No.3, Li-Hsin Road 2, Science-Based Industrial Park
City:	Hsin-Chu City
State/Country:	TAIWAN
Name:	FUJIAN JINHUA INTEGRATED CIRCUIT CO., LTD.
Street Address:	6TH FLOOR, PODIUM OF ELECTRIC POWER COMPANY BUILDING, MEILING STREET, JINJIANG CITY
City:	QUANZHOU CITY, FUJIAN PROVINCE
State/Country:	CHINA

PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	15458946

CORRESPONDENCE DATA

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using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.

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ATTORNEY DOCKET NUMBER:	NAUP2916USA
NAME OF SUBMITTER:	SIBYL YU
SIGNATURE:	/SIBYL YU/

PATENT 504271907 REEL: 041574 FRAME: 0354

DATE SIGNED:	03/14/2017
Total Attachments: 10	
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PATENT REEL: 041574 FRAME: 0355

Title of Invention:

Semiconductor storage device and manufacturing method thereof

As the below named inventor, I here This declaration is directed to:	by declare that:			
☑ The attached application, or				
☐ United States application nu	mber	filed c	n,	or
☐ PCT international application	number	file	d on	
The above-identified application was	made or authorized to be	made by me.		
I believe that I am the original inventapplication.	or or an original joint inven	tor of a claime	d invention in the	
I hereby acknowledge that any willfu under18 U.S.C. 1001 by fine or impri	l false statement made in t isonment of not more than	his declaration five (5) years,	is punishable or both.	
In consideration of the payment by	UNITED MICROELEC CORP.	TRONICS	having a postal addr	ess of
No.3, Li-Hsin Road 2, Science	-Based Industrial Par	k, Hsin-Chu	City 300, Taiwan,	R.O.C.
(referred to as "ASSIGNEE"below) to acknowledged, andfor other good an	ol of the sum of One Dolland valuable consideration.	r (\$ 1.00), the	receipt of which is here	eby
In consideration of the payment by	Fujian Jinhua Integra Co., Ltd.	ted Circuit	having a postal addr	ess of
6th floor, Podium of electric p Quanzhou City, Fujian provin	ower company buildi ce 362200, P.R.C.	ng, Meiling	street, Jinjiang cit	y,
(referred to as "ASSIGNEE"below) to acknowledged, andfor other good an	o I of the sum of One Dolla d valuable consideration.	r (\$ 1.00), the	receipt of which is here	eby
I hereby sell, assign and transfer to A the entire right, title and interest in ar invention as above-identified applica invention by the above application or substitutes, or extensions thereof, ar	nd to any and all improvem tion and, in and to, all Lette any continuations, continu	ents which are ers Patent to b uation-in-part, o	disclosed in the e obtained for said divisions, renewals,	E
I hereby covenant that no assignmer entered into which would conflict with		imbrance has	been or will be made o	or
I further covenant that ASSIGNEE w and documents relating to said inven- known and accessible to I and will te related thereto and will promptly exe-	ition and said Letters Pater stify as to the same in any	nt and legal eq interference, l	uivalents as may be itigation proceeding	5

Page 1 of 10

NPO#NAU-P2916-USA:0 CUST#UMCF-2016-0105

Docket No NA	AUP2	2916	SUSA.
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maintain, is equivalents	sue any and all papers, instruments or amidations and enforce said application, said invention thereof which may be necessary or desirable SS WHEREOF, I have hereunto set hand and	on and sai to carry o	d Letters Pate ut the proposi	ent and sa	
	oplication data sheet (PTO/SB/14 or equivalen ntity, must accompany this form. Use this form		g naming the	entire	
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LEGAL NAI	ME OF INVENTOR(ASSIGNOR)				
Inventor:	Feng-Yi Chang	Date:	MAR 1 4	2017	
Signature:	Feng-Yi Chang				

Page 2 of 10

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In consideration of the payment by	UNITED MICROEL	ECTRONICS	having a postal ad	idress of	
No.3, Li-Hsin Road 2, Science	-Based Industrial	Park, Hsin-Chu	 ı City 300, Taiwa	n, R.O.C.	
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In consideration of the payment by	Fujian Jinhua Inte Co., Ltd.	grated Circuit	having a postal ac	dress of	
6th floor, Podium of electric p Quanzhou City, Fujian provin	ower company bu ce 362200, P.R.C.	ilding, Meiling	street, Jinjiang	city,	
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I hereby sell, assign and transfer to a the entire right, title and interest in a invention as above-identified applica invention by the above application of substitutes, or extensions thereof, ar	nd to any and all impro tion and, in and to, all l any continuations, co	vements which are Letters Patent to b ntinuation-in-part,	e disclosed in the be obtained for said divisions, renewals,		
I hereby covenant that no assignment entered into which would conflict with		encumbrance has	been or will be mad	le or	
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Page 3 of 10

Note: An application data sheet (PTO/SB/14 or equivalent), including naming the entire inventive entity, must accompany this form. Use this form for each additional inventor. LEGAL NAME OF INVENTOR(ASSIGNOR) Inventor: Fu-Che Lee Date: MAR 1 4 2017 Signature: Lee Date: MAR 1 4 2017	maintain, is equivalents	tives any and all papers, instruments or attide isue and enforce said application, said invent thereof which may be necessary or desirable ESS WHEREOF, I have hereunto set hand ar	tion and sai e to carry o	d Letters Patent ut the proposes	and said thereof.	ite of signing)
Inventor: Fu-Che Lee Date: MAR 1 4 2017	Note: An a inventive e	oplication data sheet (PTO/SB/14 or equivale ntity, must accompany this form. Use this for	ent), includir m for <u>each</u> :	ng naming the ei additional invent	ntire or.	
Inventor: Fu-Che Lee Date: MAR 1 4 2017						
MAR 1 4 2017	LEGAL NA	ME OF INVENTOR(ASSIGNOR)				
Signature: Lu-che Lee	Inventor:	Fu-Che Lee	Date:	MAR 142	017	
	Signature:	Zu-de Lee				

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In consideration of the payment by	Fujian Jinhua Into Co., Ltd.	egrated Circuit	having a postal	l address of
6th floor, Podium of electric p Quanzhou City, Fujian provin		uilding, Meiling	- street, Jinjian	g city,
(referred to as "ASSIGNEE"below) to acknowledged, andfor other good and			receipt of which i	is hereby
I hereby sell, assign and transfer to a the entire right, title and interest in a invention as above-identified applica- invention by the above application o substitutes, or extensions thereof, an	nd to any and all impro ition and, in and to, all r any continuations, co	ovements which are Letters Patent to b ontinuation-in-part, o	e disclosed in the e obtained for sa divisions, renewa	e aid als.
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Page 5 of 10

NPO#NAU-P2916-USA:0 CUST#UMCF-2016-0105

Page 6 of 10

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(referred to as "ASSIGNEE"below) to I of the sum of One Dollar (\$ 1.00), the receipt of which is hereby acknowledged, and for other good and valuable consideration.						
In consideration of the payment by	Fujian Jinhua Integrate Co., Ltd.	ed Circuit having a po	ostal address of			
6th floor, Podium of electric power company building, Meiling street, Jinjiang city, Quanzhou City, Fujian province 362200, P.R.C.						
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I hereby sell, assign and transfer to A the entire right, title and interest in ar invention as above-identified application or substitutes, or extensions thereof, and	d to any and all improvemen ion and, in and to, all Letters any continuations, continuat	nts which are disclosed in Patent to be obtained fo tion-in-part, divisions, ren	n the or said newals,			
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Page 9 of 10

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maintain, issu	es any and all papers, instruments or affida ue and enforce said application, said inventi hereof which may be necessary or desirable	on and said	Letters Patent and s				
	S WHEREOF, I have hereunto set hand an		MAR 1 4 2017	(Date of signing)			
Note: An application data sheet (PTO/SB/14 or equivalent), including naming the entire inventive entity, must accompany this form. Use this form for <u>each additional inventor.</u>							
LEGAL NAM	E OF INVENTOR(ASSIGNOR)			•			
Inventor:	Hsien-Shih Chu	Date:	MAR 1 4 2017				
Signature;	Hsien-Shih Chu			,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,			

Page 10 of 10

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RECORDED: 03/14/2017

F#NPÖ-P0002E-US1201 DSB0-105U032504

PATENT REEL: 041574 FRAME: 0365